

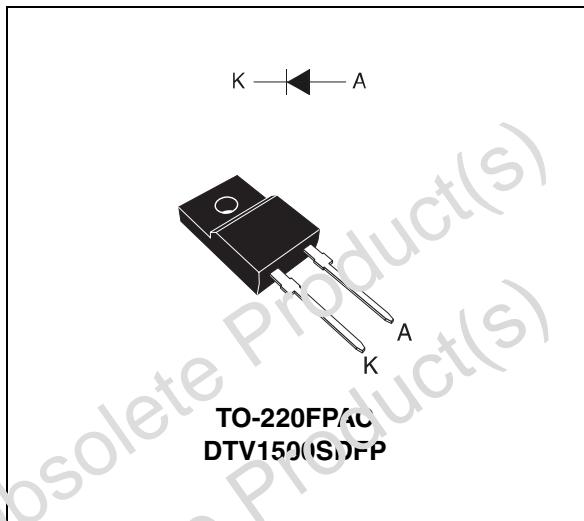


DTV1500SD

(CRT TV HORIZONTAL DEFLECTION) HIGH VOLTAGE DAMPER DIODE

Table 1: Main Product Characteristics

$I_{F(AV)}$	6 A
$I_{F\text{peak}} \text{ (max)}$	12 A
V_{RRM}	1500 V
T_j	175°C
$V_F \text{ (typ)}$	1.1 V
$t_{rr} \text{ (typ)}$	150 ns
$V_{FP} \text{ (typ)}$	26 V



FEATURES AND BENEFITS

- High breakdown voltage capability
- Specified turn on switching characteristics
- Very fast recovery diode
- Low static and peak forward voltage drop for low dissipation
- Insulated package (TO-220FPAC):
Insulating voltage = 2000V DC
Capacitance = 12 pF
- Planar technology allowing high quality and best electrical characteristics

Table 2: Order Code

Part Number	Marking
DTV1500SDFP	DTV1500SDFP

DESCRIPTION

High voltage diode especially designed for horizontal deflection stage in standard and high resolution displays for TVs.

This device is packaged in TO-220FPAC (insulated package).

Table 3: Absolute Maximum Ratings

Symbol	Parameter		Value	Unit
V_{RRM}	Repetitive peak reverse voltage		1500	V
$I_{F(\text{RMS})}$	RMS forward voltage		15	A
$I_{F\text{peak}}$	Peak working forward current	$f = 56\text{kHz}$	12	A
I_{FSM}	Surge non repetitive forward current	$t_p = 10\text{ms}$ sinusoidal	50	A
T_{stg}	Storage temperature range		-65 to 175	°C
T_j	Maximum operating junction temperature		175	°C

DTV1500SD

Table 4: Thermal Resistance

Symbol	Parameter	Value (max.)	Unit
R _{th(j-c)}	Junction to case thermal resistance	5.8	°C/W

Table 5: Static Electrical Characteristics

Symbol	Parameter	Test conditions		Typ	Max.	Unit
I _R *	Reverse leakage current	T _j = 25°C	V _R = V _{RRM}		100	µA
		T _j = 125°C		100	1000	
V _F **	Forward voltage drop	T _j = 25°C	I _F = 6A	1.2	1.75	V
		T _j = 125°C		1.1	1.5	

Pulse test: * tp = 5 ms, δ < 2%

** tp = 380 µs, δ < 2%

To evaluate the conduction losses use the following equation: P = 1.23 × I_{F(AV)} + 0.045 I_F² (RMS)

Table 6: Recovery Characteristics

Symbol	Parameter	Test conditions		Typ	Max.	Unit
t _{rr}	Reverse recovery time	T _j = 25°C	I _F = 1A	I _F /dI _F /dt = -50 A/µs	V _R = 30V	150
			I _F = 100mA	I _{rr} = 10mA	I _R = 100mA	250
					1000	ns

Table 7: Turn-On Switching Characteristics

Symbol	Parameter	Test conditions		Typ	Max.	Unit
t _{fr}	Forward recovery time	T _j = 100°C	I _F = 6A	dI _F /dt = 80 A/µs	V _{FR} = 3V	500 ns
V _{FP}	Peak forward voltage	T _j = 100°C	I _F = 6A	dI _F /dt = 80 A/µs		26 36 V

Figure 1: Conduction losses versus average current ($\delta=0.45$)

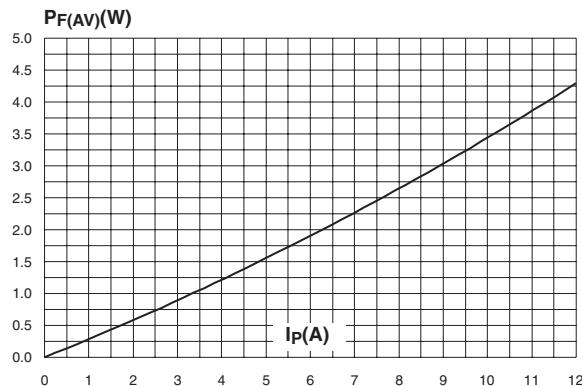


Figure 3: Reverse recovery charges versus dI_F/dt (typical values)

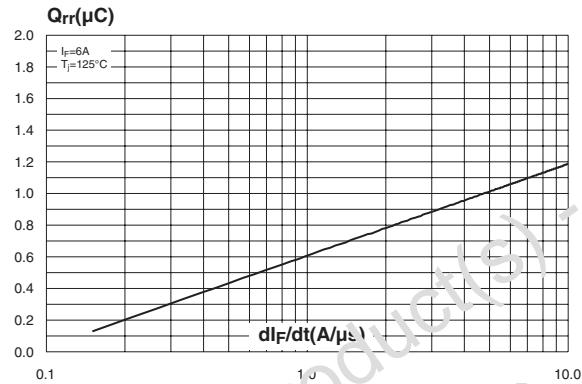


Figure 5: Transient peak forward voltage versus dI_F/dt (typical values)

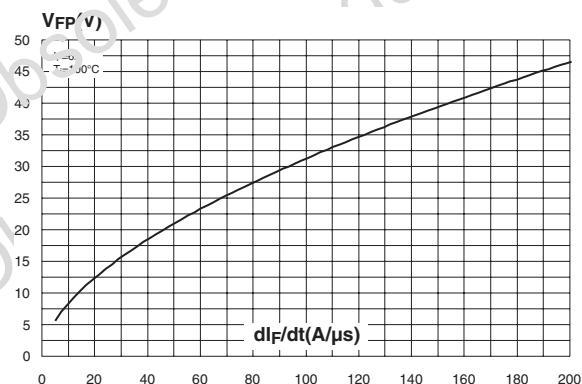


Figure 2: Forward voltage drop versus forward current

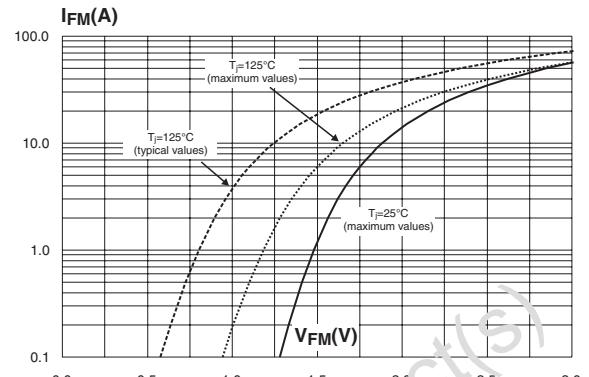


Figure 4: Peak reverse recovery current versus dI_F/dt (typical values)

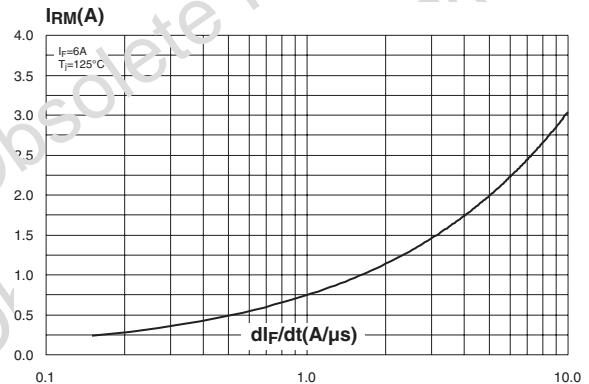


Figure 6: Forward recovery time versus dI_F/dt (typical values)

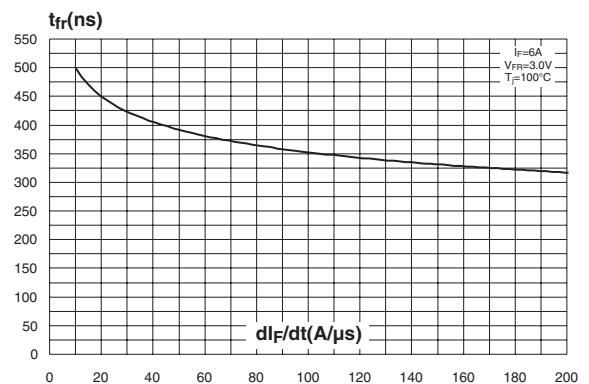


Figure 7: Relative variations of dynamic parameters versus junction temperature

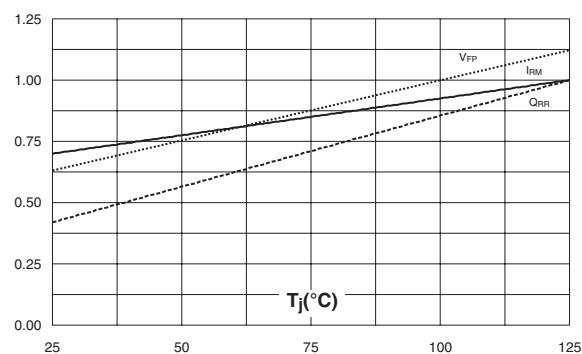


Figure 8: Junction capacitance versus reverse voltage applied (typical values)

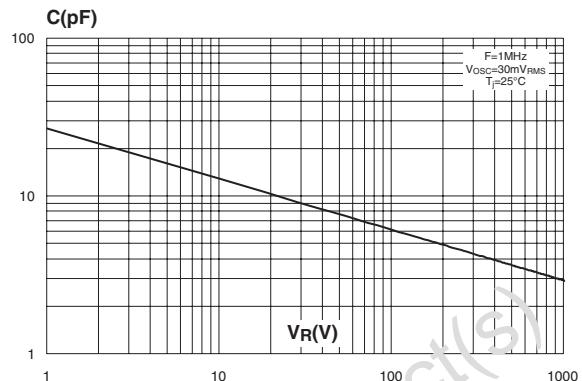


Figure 9: Relative variation of thermal impedance junction case versus pulse duration

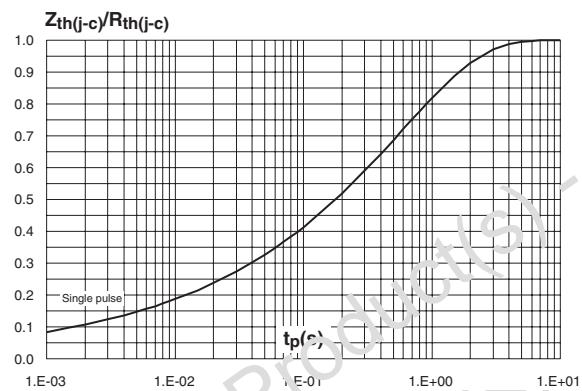


Figure 10: TO-220FPAC Package Mechanical Data

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.4	4.6	0.173	0.181
B	2.5	2.7	0.098	0.106
D	2.5	2.75	0.098	0.108
E	0.45	0.70	0.017	0.027
F	0.75	1	0.030	0.039
F1	1.15	1.70	0.045	0.067
F2	1.15	1.70	0.045	0.067
G	4.95	5.20	0.195	0.204
G1	2.40	2.70	0.094	0.106
H	10	10.4	0.393	0.409
L2	16 Typ.		0.63 Typ.	
L3	28.6	30.6	1.126	1.204
L4	9.8	10.6	0.385	0.417
L6	15.9	16.4	0.626	0.645
L7	9.00	9.30	0.354	0.366
Dia.	3	3.20	0.118	0.126

Table 8: Ordering Information

Part Number	Marking	Package	Weight	Base qty	Delivery mode
DTV1500SDFP	DTV1500SDFP	TO-220FPAC	1.8 g	50	Tube

Table 9: Revision History

Date	Revision	Description of Changes
05-Jul-2004	1	First issue.
25-Nov-2004	2	Table 3 page 1: T_{stg} and T_j from upgraded from 150°C to 175°C.
16-Mar-2005	3	I_{Fpeak} parameter included.

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